

Session Program

25-28 Jun 2006

8th RD50 Workshop

Pad Detector Characterization

Prague

Tuesday 27 June

10:50

Pad Detector Characterization

Session | Location: Prague

10:50-11:10

Study of radiation damage induced by protons and neutrons on heavily irradiated Magnetic Czochralski and Epitaxial silicon detectors

Speaker

Norman Manna

11:10-11:30

Trapping of electrons and holes in p-type silicon irradiated with neutrons

Speaker

Vladimir Cindro

11:30-12:10

Long term annealing of neutron irradiated detectors evaluated at LHC operational temperatures

Speaker

Elena Verbitskaya

12:10-12:30

CV and CCE characterization of p-type MCZ Material

Speaker

Herbert Hoedlmoser

12:30-14:00

Lunch break

14:00-15:00

Discussion session on Defect Engineering and Pad Detector Characterization

15:00